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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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# RENESAS

# HAF2007(L), HAF2007(S)

# Silicon N Channel MOS FET Series Power Switching

REJ03G1137-0400 (Previous: ADE-208-706B) Rev.4.00 Sep 07, 2005

### Description

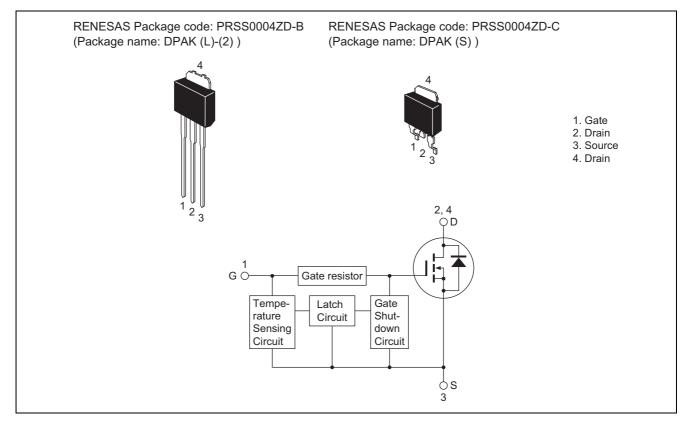
This FET has the over temperature shut-down capability sensing to the junction temperature.

This FET has the built-in over temperature shut-down circuit in the gate area. And this circuit operation to shut-down the gate voltage in case of high junction temperature like applying over power consumption, over current etc.

### Features

- Logic level operation (4 to 6 V Gate drive)
- High endurance capability against to the short circuit
- Built-in the over temperature shut-down circuit
- Latch type shut-down operation (Need 0 voltage recovery)

### Outline





### **Absolute Maximum Ratings**

			(Ta = 25°C)
Item	Symbol	Value	Unit
Drain to source voltage	V <sub>DSS</sub>	60	V
Gate to source voltage	V <sub>GSS</sub>	16	V
	V <sub>GSS</sub>	-2.5	V
Drain current	I <sub>D</sub>	5	А
Drain peak current	I <sub>D (pulse)</sub> Note 1	10	А
Body-drain diode reverse drain current	I <sub>DR</sub>	5	А
Channel dissipation	Pch Note 2	20	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C
	-		

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Value at Tc =  $25^{\circ}$ C

# **Typical Operation Characteristics**

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Input voltage	VIH	3.5	_	_	V	
	VIL	—	_	1.2	V	
Input current	I <sub>IH1</sub>	—		100	μA	$Vi = 8 V, V_{DS} = 0$
(Gate non shut down)	I <sub>IH2</sub>	—		50	μA	$Vi = 3.5 V, V_{DS} = 0$
	IIL	—		1	μA	Vi = 1.2 V, V <sub>DS</sub> = 0
Input current	I <sub>IH (sd) 1</sub>	—	0.8	_	mA	$Vi = 8 V, V_{DS} = 0$
(Gate shut down)	I <sub>IH (sd) 2</sub>	—	0.35	_	mA	$Vi = 3.5 V, V_{DS} = 0$
Shut down temperature	Tsd	—	175		°C	Channel temperature
Gate operation voltage	V <sub>OP</sub>	3.5		12	V	



### **Electrical Characteristics**

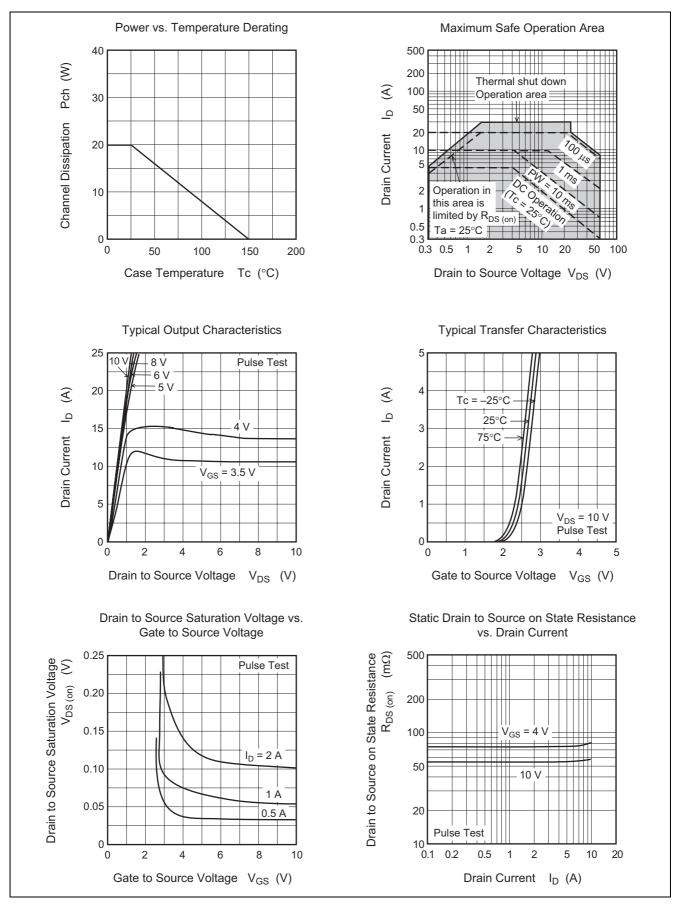
						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain current	I <sub>D1</sub>	4			А	$V_{GS} = 3.5 \text{ V}, V_{DS} = 2 \text{ V}$
	I <sub>D2</sub>	—		10	mA	$V_{GS} = 1.2 \text{ V}, V_{DS} = 2 \text{ V}$
Drain to source breakdown voltage	V (BR) DSS	60	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V (BR) GSS	16			V	$I_G = 300 \ \mu A, \ V_{DS} = 0$
	V (BR) GSS	-2.5			V	$I_G = -100 \ \mu A, V_{DS} = 0$
Gate to source leak current	I <sub>GSS1</sub>	—		100	μΑ	$V_{GS} = 8 V, V_{DS} = 0$
	I <sub>GSS2</sub>	—		50	μΑ	$V_{GS} = 3.5 V, V_{DS} = 0$
	I <sub>GSS3</sub>	—		1	μΑ	$V_{GS} = 1.2 \text{ V}, V_{DS} = 0$
	I <sub>GSS4</sub>	—		-100	μΑ	$V_{GS} = -2.4 \text{ V}, V_{DS} = 0$
Input current (shut down)	I <sub>GS (op) 1</sub>	—	0.8		mA	$V_{GS} = 8 V, V_{DS} = 0$
	I <sub>GS (op) 2</sub>	—	0.35		mA	$V_{GS} = 3.5 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	—		10	μΑ	$V_{DS} = 60 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	V <sub>GS (off)</sub>	1.0		2.25	V	$I_{D} = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Forward transfer admittance	y <sub>fs</sub>	4	7.5		S	$I_D = 2.5 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note 3}}$
Static drain to source on state resistance	R <sub>DS (on)</sub>	—	73	120	mΩ	$I_D = 2.5 \text{ A}, V_{GS} = 4 \text{ V}^{Note 3}$
	R <sub>DS (on)</sub>	—	55	75	mΩ	$I_D = 2.5 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note 3}}$
Output capacitance	Coss	—	270		pF	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0$
						f = 1 MHz
Turn-on delay time	t <sub>d (on)</sub>	—	2.8	_	μs	I <sub>D</sub> = 2.5 A
Rise time	tr	—	12.4	_	μs	$V_{GS} = 5 V$
Turn-off delay time	t <sub>d (off)</sub>	—	15		μs	$R_L = 12 \Omega$
Fall time	t <sub>f</sub>	—	11		μs	
Body-drain diode forward voltage	V <sub>DF</sub>	—	0.9		V	$I_F = 5 A, V_{GS} = 0$
Body-drain diode reverse recovery time	t <sub>rr</sub>	—	140		ns	$I_F = 5 A, V_{GS} = 0$
						di <sub>F</sub> /dt = 50 A/µs
Over load shut down operation time Note4	t <sub>os1</sub>	—	1.1		ms	$V_{GS}$ = 5 V, $V_{DD}$ = 16 V
	t <sub>os2</sub>	—	0.57		ms	$V_{GS} = 5 \text{ V}, V_{DD} = 24 \text{ V}$

Notes: 3. Pulse test

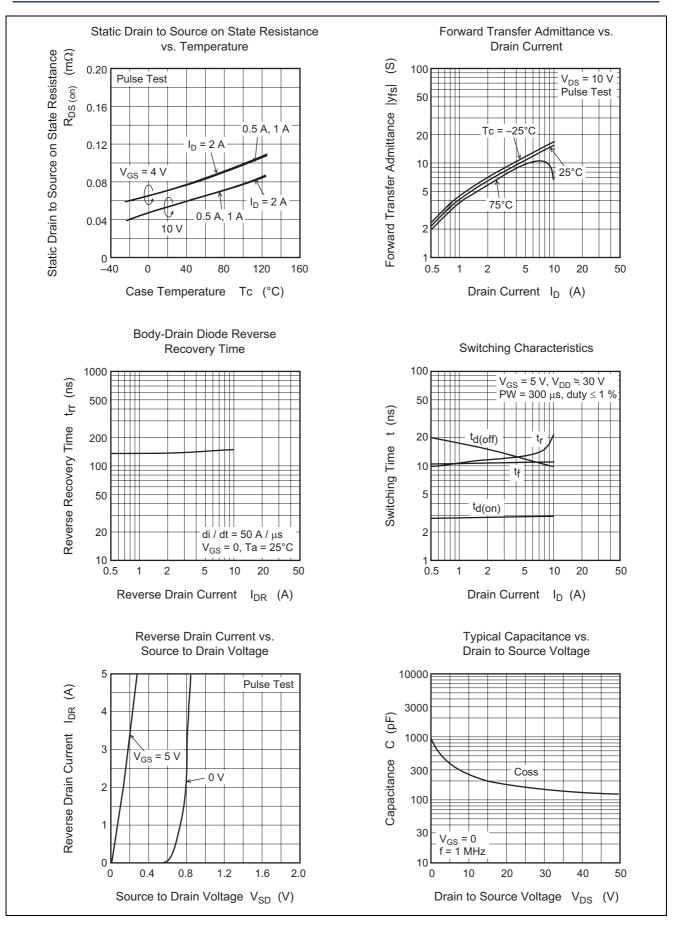
4. Including the junction temperature rise of the over loaded condition.



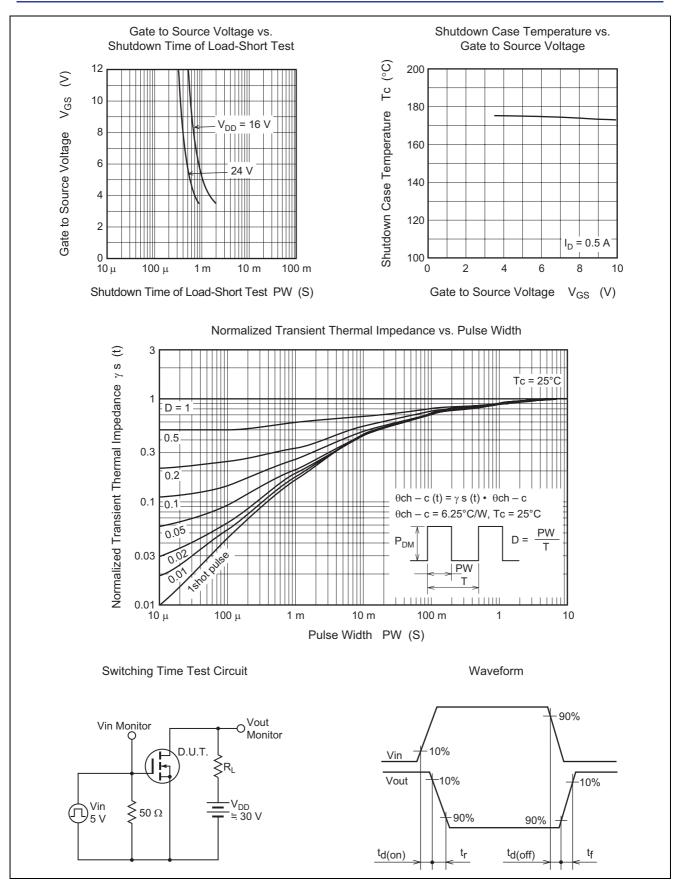
#### **Main Characteristics**





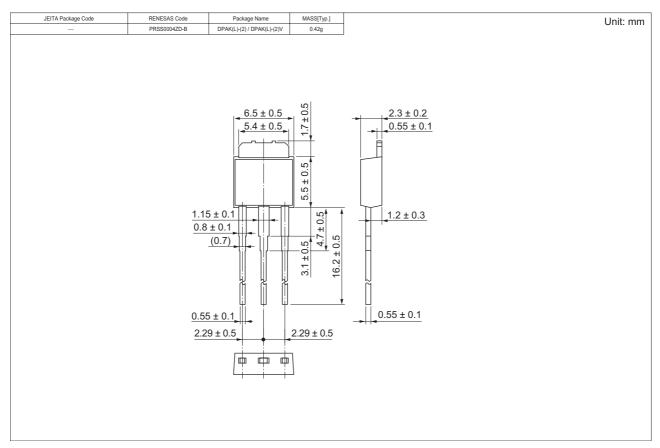


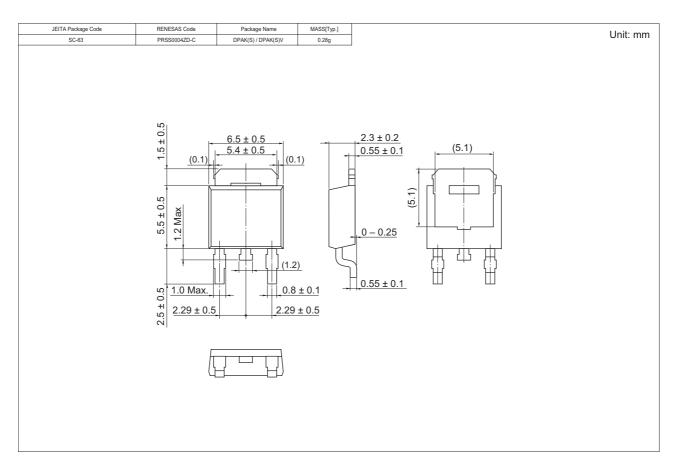




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#### **Package Dimensions**







# **Ordering Information**

Part Name	Quantity	Shipping Container
HAF2007-90L	Max: 100 pcs/sack	Sack
HAF2007-90S	Max: 100 pcs/sack	Sack
HAF2007-90STL	3000 pcs/Reel	Embossed tape
HAF2007-90STR	3000 pcs/Reel	Embossed tape

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